

VOLTAGE RANGE: 50 - 1000V

CURRENT: 2.0 A



Features

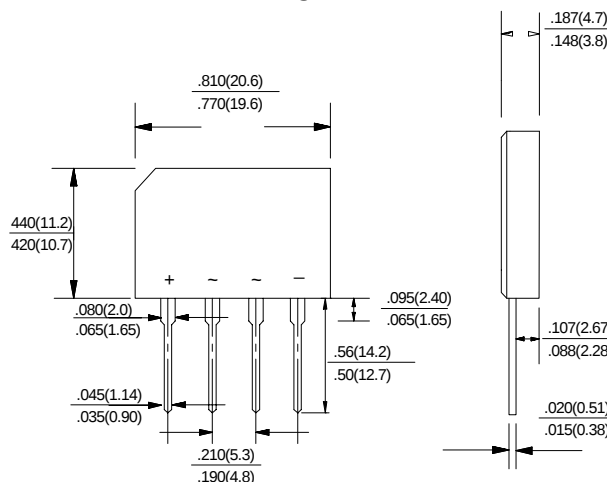
- Diffused Junction
- High Surge Current Capability
- High Current Capability
- High Reliability

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Weight: 2.0 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



KBJ2



Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBJ2A	KBJ2B	KBJ2D	KBJ2G	KBJ2J	KBJ2K	KBJ2M	Unit
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @ $T_A = 50^\circ\text{C}$	$I_F(AV)$	2.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	50.0							A
Maximum instantaneous forward voltage at 1.0 A	V_F	1.0							V
Maximum reverse current @ $T_A = 25^\circ\text{C}$	I_R	10.0							μA
at rated DC blocking voltage @ $T_A = 100^\circ\text{C}$		1.0							mA
Typical junction capacitance per element	C_J	45							pF
Typical thermal resistance	$R_{\theta JC}$	2.2							$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ---- + 125							$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ---- + 150							$^\circ\text{C}$

NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC

2. Device mounted on 300mm X 300mm X 1.6mm cu Plate heatsink.

FIG.1 – PEAK FORWARD SURGE CURRENT

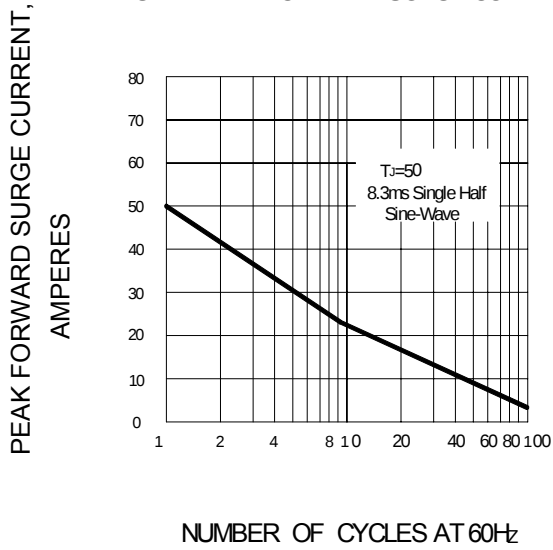


FIG.2 – FORWARD DERATING CURVE

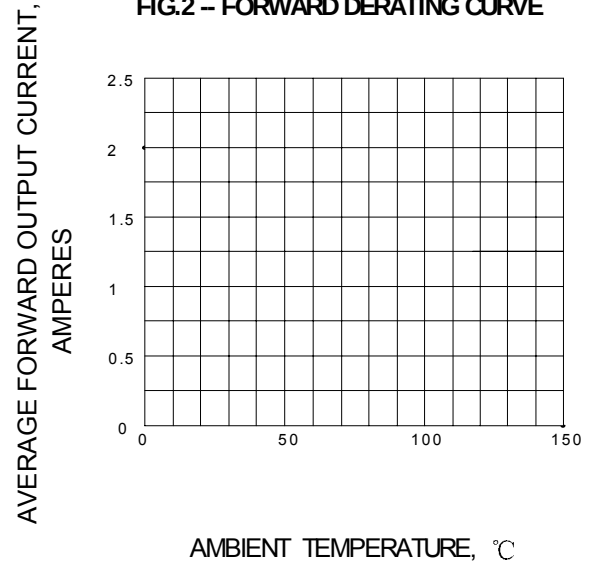


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

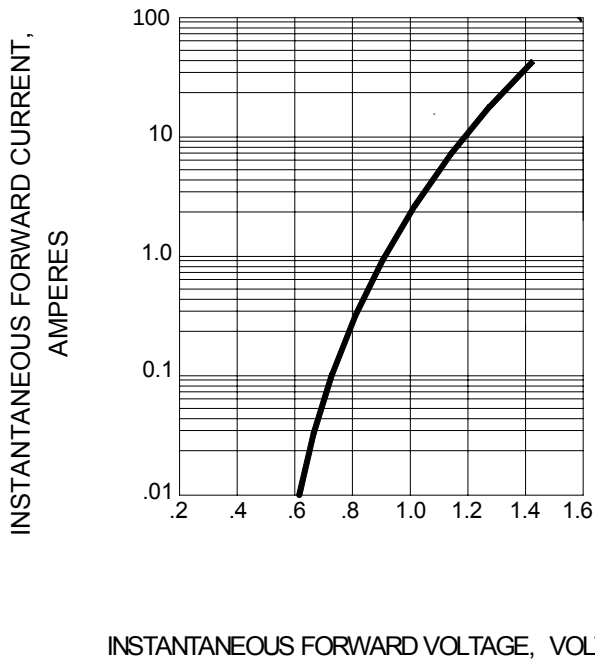


FIG.4 – TYPICAL JUNCTION CAPACITANCE

